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BUL310FP

HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

- STMicroelectronics PREFERRED SALESTYPE
- NPN TRANSISTOR
- HIGH VOLTAGE CAPABILITY
- LOW SPREAD OF DYNAMIC PARAMETERS
- MINIMUM LOT-TO-LOT SPREAD FOR RELIABLE OPERATION
- VERY HIGH SWITCHING SPEED
- FULLY CHARACTERIZED AT 125°C
- LARGE RBSOA
- FULLY MOLDED INSULATED PACKAGE
- 2000 V DC INSULATION (U.L. COMPLIANT)

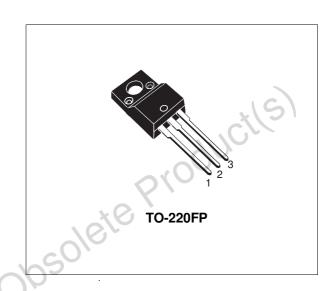
APPLICATIONS

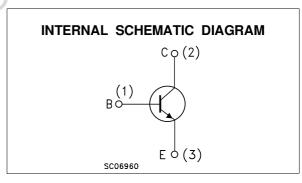
- HORIZONTAL DEFLECTION FOR COLOUR TV
- ELECTRONIC BALLASTS FOR FLUORESCENT LIGHTING
- FLYBACK AND FORWARD SINGLE TRANSISTOR LOW POWER CONVERTERS

DESCRIPTION

The BUL310FP is manufactured using high voltage Multi Epitaxial Planar technology for high switching speeds and high voltage capability. It uses a Cellular Emitter structure with planar edge termination to enhance switching speeds while maintaining a wide RBSOA.

The BUL series is designed for use in lighting applications and low cost switch-mode power supplies.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V _{CES}	Collector-Emitter Voltage (V _{BE} = 0)	1000	V	
V _{CEO}	Collector-Emitter Voltage (I _B = 0)	500	V	
V_{EBO}	Emitter-Base Voltage (I _C = 0)	9		
Ic	Collector Current	5	A	
I _{CM}	Collector Peak Current (t _p <5 ms)	10	Α	
Ι _Β	Base Current	3	Α	
I _{BM}	Base Peak Current (t _p <5 ms)	4	Α	
P _{tot}	Total Dissipation at Tc = 25 °C	36	W	
T _{stg}	Storage Temperature	-65 to 150	°C	
T _i	Max. Operating Junction Temperature	150	°C	

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THERMAL DATA

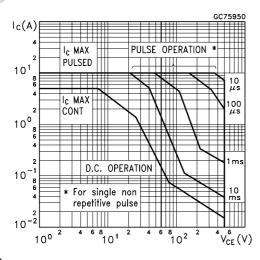
R _{thj-case}	Thermal Resistance Junction-Case	Max	3.5	°C/W	
$R_{thj-amb}$	Thermal Resistance Junction-Ambient	Max	62.5	°C/W	

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

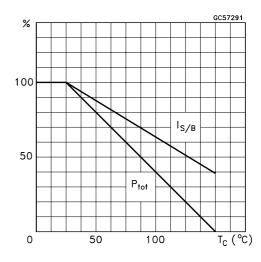
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut-off Current (V _{BE} = 0)	$V_{CE} = 1000 \text{ V}$ $V_{CE} = 1000 \text{ V}$ $T_j = 125 ^{\circ}\text{C}$			100 500	μ Α μ Α
I _{CEO}	Collector Cut-off Current (I _B = 0)	V _{CE} = 500 V			250	μА
$V_{CEO(sus)^{*}}$	Collector-Emitter Sustaining Voltage (I _B = 0)	I _C = 100 mA	500		Cil.	34
V_{EBO}	Emitter-Base Voltage (I _C = 0)	I _E = 10 mA	9	6		V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	PY		0.5 0.7 1.1	V V V
V _{BE(sat)*}	Base-Emitter Saturation Voltage	I _C = 1 A I _B = 0.2 A I _C = 2 A I _B = 0.4 A I _C = 3 A I _B = 0.6 A	,		1 1.1 1.2	V V V
h _{FE} *	DC Current Gain	$I_{C} = 10 \text{ mA}$ $V_{CE} = 5 \text{ V}$ $I_{C} = 3 \text{ A}$ $V_{CE} = 2.5 \text{ V}$	10 6	10	14	
t _s t _f	INDUCTIVE LOAD Storage Time Fall Time	$\begin{array}{lll} I_{C} = 2 \; A & I_{B1} = 0.4 \; A \\ V_{BE(off)} = \text{-5 V} & R_{BB} = 0 \; \Omega \\ V_{CL} = 250 \; V & L = 200 \; \mu\text{H} \\ (\text{see figure 1}) & & & & \\ \end{array}$		1.2 80	1.9 160	μs ns
t _s t _f	INDUCTIVE LOAD Storage Time Fall Time	$\begin{array}{lll} I_{C} = 2 \; A & I_{B1} = 0.4 \; A \\ V_{BE(off)} = \text{-5V} & R_{BB} = 0 \; \Omega \\ V_{CL} = 250 \; V & L = 200 \; \mu\text{H} \\ T_{j} = 125 \; ^{\circ}\text{C} & (\text{see figure 1}) \end{array}$		1.8 150		μs ns

^{*} Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

Safe Operating Areas



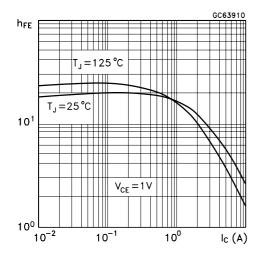
Derating Curve



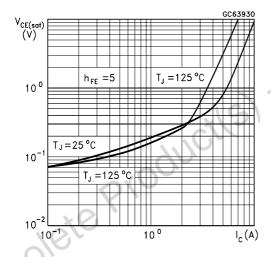
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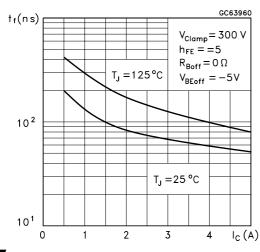
DC Current Gain



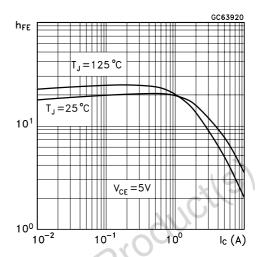
Collector Emitter Saturation Voltage



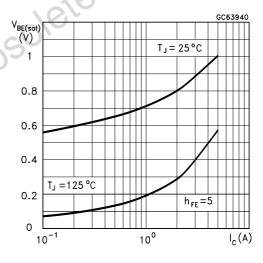
Inductive Load Fall Time



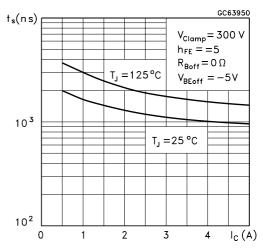
DC Current Gain



Base Emitter Saturation Voltage



Inductive Load Storage Time



Reverse Biased SOA

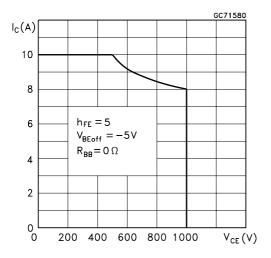
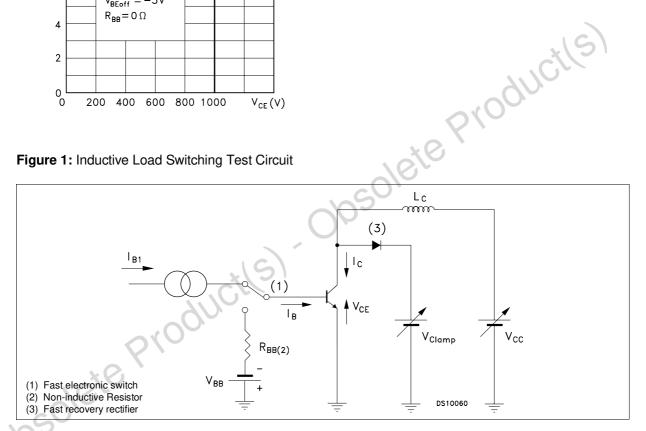


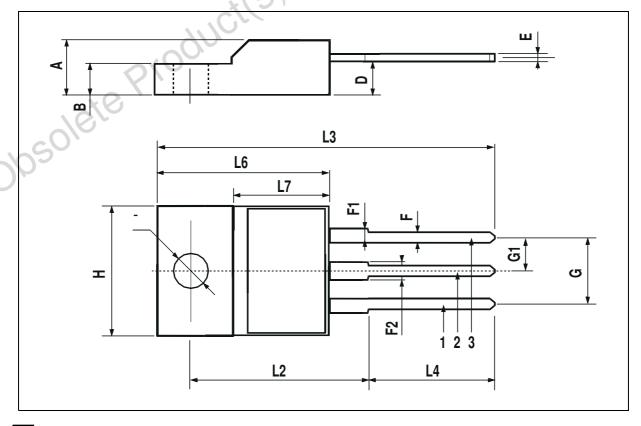
Figure 1: Inductive Load Switching Test Circuit



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TO-220FP MECHANICAL DATA

DIM.	mm			inch			
DIIVI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	4.4		4.6	0.173		0.181	
В	2.5		2.7	0.098		0.106	
D	2.5		2.75	0.098		0.108	
Е	0.45		0.7	0.017		0.027	
F	0.75		1	0.030		0.039	
F1	1.15		1.7	0.045		0.067	
F2	1.15		1.7	0.045		0.067	
G	4.95		5.2	0.195	900	0.204	
G1	2.4		2.7	0.094	240	0.106	
Н	10		10.4	0.393		0.409	
L2		16		100	0.630		
L3	28.6		30.6	1.126		1.204	
L4	9.8		10.6	0.385		0.417	
L6	15.9		16.4	0.626		0.645	
L7	9		9.3	0.354		0.366	
Ø	3	16	3.2	0.118		0.126	



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